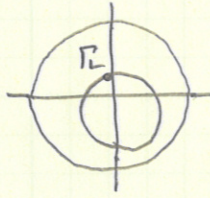


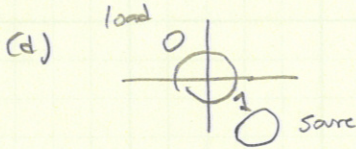
① Bilateral design

(a) $G_P, \text{max} = 12.7 \text{ dB}$

(b)



(c) $\Gamma_S = 0.77 \angle 120^\circ, \Gamma_L = 0.35 \angle 107^\circ$



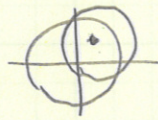
Both circles are outside the unit circle
The transistor is unconditionally stable.

② (a) $F = 0.77 \text{ dB}, T_{eq} = 56 \text{ K}$

(b) $P_{S, \text{in}} = -106 \text{ dBm}$

(c) $DR = 93 \text{ dB}$

③ $\Gamma_S = \Gamma_{opt},$



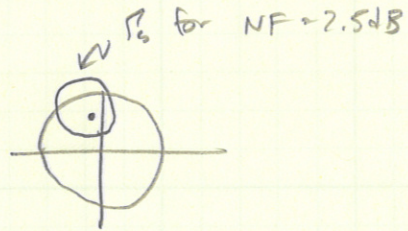
$\Gamma_L = 0.45 \angle 60^\circ, r_L = 0.5$

 Γ_L can be anywhere on this circle.

④ $NF = 2.5 \text{ dB}, \text{max. gain}$

$N = 0.14, C_F = 0.71 \angle 100^\circ, r = 0.3$

Conjugate match the load: $\Gamma_L = 0.7 \angle 60^\circ$



⑤ At resonance, $j\omega L = -\frac{1}{j\omega C} \Rightarrow \omega = \frac{1}{\sqrt{LC}} = 1.4 \times 10^9 \text{ rad/s} = 225 \text{ MHz}$

$R_L, \text{max power} = \frac{R_0}{3} = 10 \Omega$